- 150-mA Load Current Without External **Power Transistor**
- Typically 0.02% Input Regulation and 0.03% Load Regulation (μA723M)
- Adjustable Current-Limiting Capability
- Input Voltages to 40 V
- Output Adjustable From 2 V to 37 V
- Direct Replacement for Fairchild µA723C and µA723M

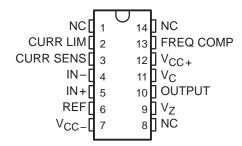
## description

The µA723C and µA723M are precision monolithic integrated circuit voltage regulators featuring high ripple rejection, excellent input and load regulation, excellent temperature stability, and low standby current. The circuit consists of a temperature-compensated reference-voltage amplifier, an error amplifier, a 150-mA output transistor, and an adjustable output current limiter.

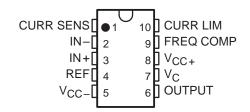
The µA723C and µA723M are designed for use in positive or negative power supplies as a series, shunt, switching, or floating regulator. For output currents exceeding 150 mA, additional pass elements may be connected as shown in Figures 4 and 5.

The µA723C is characterized for operation from 0°C to 70°C. The μA723M is characterized for operation over the full military temperature range of -55°C to 125°C.

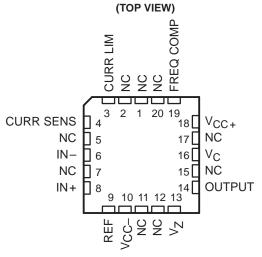
### μΑ723C . . . D OR N PACKAGE $\mu$ A723M . . . J PACKAGE (TOP VIEW)



### $\mu$ A723M . . . U PACKAGE (TOP VIEW)



# μΑ723M ... FK PACKAGE



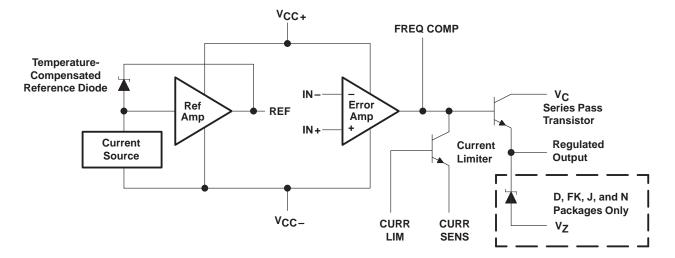
NC - No internal connection



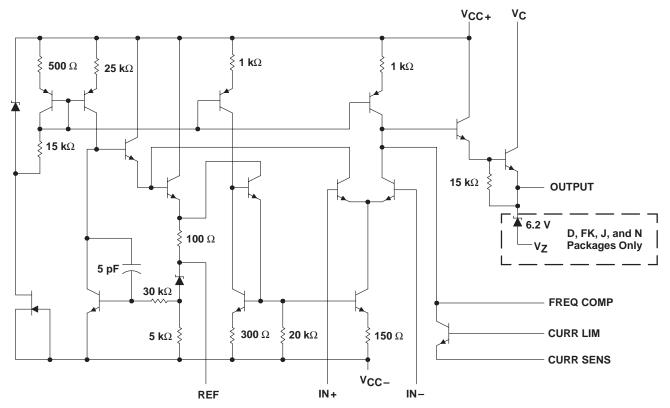
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## functional block diagram



### schematic

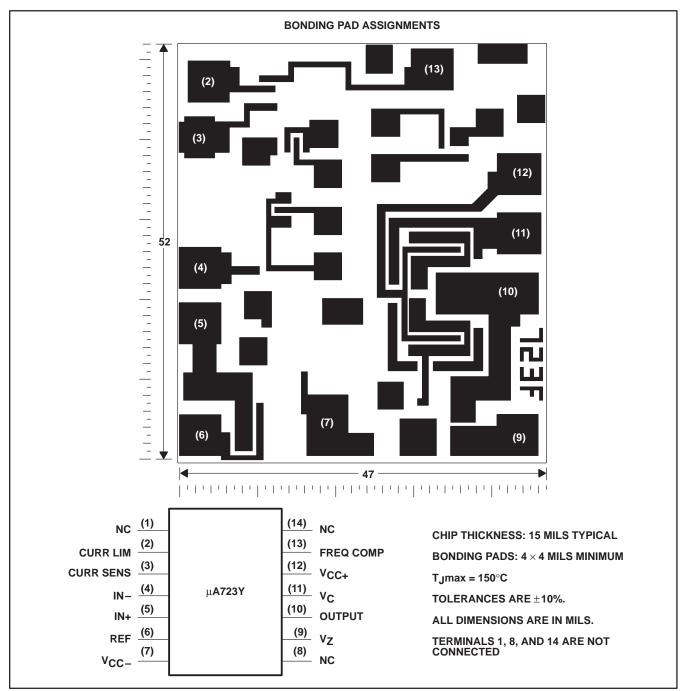


Resistor and capacitor values shown are nominal.



## μΑ723Y chip information

This chip, when properly assembled, displays characteristics similar to the  $\mu$ A723C. Thermal compression or ultrasonic bonding can be used on the doped aluminum bonding pads. The chips can be mounted with conductive epoxy or a gold-silicon preform.



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# absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Peak voltage from $V_{CC+}$ to $V_{CC-}$ ( $t_w \le 50 \text{ ms}$ )	50 V
Continuous voltage from V <sub>CC+</sub> to V <sub>CC-</sub>	40 V
Input-to-output voltage differential	40 V
Differential input voltage to error amplifier	±5 V
Voltage between noninverting input and V <sub>CC</sub>	8 V
Current from V <sub>Z</sub>	25 mA
Current from REF	15 mA
Continuous total dissipation (see Note 1)	See Dissipation Rating Table
Continuous total dissipation (see Note 1)	
Operating free-air temperature range, $T_A$ : $\mu A723C$ $\mu A723M$	0°C to 70°C –55°C to 125°C
Operating free-air temperature range, $T_A$ : $\mu A723C$ $\mu A723M$	0°C to 70°C –55°C to 125°C
Operating free-air temperature range, T <sub>A</sub> : μA723C	0°C to 70°C 55°C to 125°C 65°C to 150°C
Operating free-air temperature range, T <sub>A</sub> : $\mu$ A723C	0°C to 70°C 55°C to 125°C 65°C to 150°C 260°C
Operating free-air temperature range, T $_A$ : $\mu$ A723C $\mu$ A723M Storage temperature range, T $_{stg}$ Case temperature for 60 seconds, T $_C$ : FK package	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: Power dissipation =  $[I_{(standby)} + I_{(ref)}] V_{CC} + [V_C - V_O] I_O$ .

### **DISSIPATION RATING TABLE**

PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C POWER}$ RATING	DERATING FACTOR	DERATE ABOVE T <sub>A</sub>	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 125°C POWER RATING
D	950 mW	7.6 mW/°C	25°C	608 mW	_
FK and J	1000 mW	11.0 mW/°C	59°C	879 mW	274 mW
N	1000 mW	9.2 mW/°C	41°C	733 mW	_
U	675 mW	5.4 mW/°C	25°C	432 mW	135 mW

## recommended operating conditions

	MIN	MAX	UNIT
Input voltage, V <sub>I</sub>	9.5	40	V
Output voltage, VO	2	37	V
Input-to-output voltage differential, V <sub>C</sub> – V <sub>O</sub>	3	38	V
Output current, IO		150	mA



## electrical characteristics at specified free-air temperature (see Notes 2 and 3)

PARAMETER	TEST CONDITION	ONE T.	Tat	μ <b>Α723C</b>			μ <b>Α723Μ</b>			UNIT	
PARAMETER	TEST CONDITION	ONS	ONS TAT		TYP	MAX	MIN	TYP	MAX	UNIT	
	$V_{ } = 12 \text{ V to } V_{ } = 15 \text{ V}$		25°C		0.1	1		0.1	1		
Input regulation	$V_{ } = 12 \text{ V to } V_{ } = 40 \text{ V}$		25°C		1	5		0.2	2	mV/V	
input regulation	$V_{I} = 12 \text{ V to } V_{I} = 15 \text{ V}$		Full range			3			3	1110/0	
Pipple rejection	$f = 50 H_Z$ to 10 kHz,	$C_{ref} = 0$	25°C		74			74		dB	
Ripple rejection	f = 50 Hz to 10 kHz,	$C_{ref} = 5 \mu F$	25°C		86			86		l ub	
			25°C		-0.3	-2		-0.3	-1.5		
Output regulation			Full			-6			-6	mV/V	
			range								
Reference voltage, V <sub>ref</sub>			25°C	6.8	7.15	7.5	6.95	7.15	7.35	V	
Standby current	V <sub>I</sub> = 30 V,	I <sub>O</sub> = 0	25°C		2.3	4		2.3	3.5	mA	
Temperature coefficient of output voltage			Full range		0.003	0.015		0.002	0.015*	%/°C	
Short-circuit output current	$R_{SC} = 10 \Omega$ ,	V <sub>O</sub> = 0	25°C		65			65		mA	
Outrout resises walteres	BW = 100 Hz to 10 kHz,	$C_{ref} = 0$	25°C		20			20		/	
Output noise voltage	BW = 100 Hz to 10 kHz,	C <sub>ref</sub> = 5 μF	25°C		2.5			2.5		μV	

<sup>\*</sup>On products compliant to MIL-STD-883, Class B, this parameter is not production tested.

## electrical characteristics, T<sub>A</sub> = 25°C (see Notes 2 and 3)

PARAMETER	TEST CONDITIONS			μ <b>Α723Υ</b>		
PARAMETER	TEST CONDIT	MIN	TYP	MAX	UNIT	
Input regulation	$V_{I} = 12 \text{ V to } V_{I} = 15 \text{ V}$		0.1			mV/V
Imput regulation	V <sub>I</sub> = 12 V to V <sub>I</sub> = 40 V			1		
Ripple rejection	$f = 50 H_Z$ to 10 kHz,	$C_{ref} = 0$		74		dB
Kipple rejection	$f = 50 \text{ Hz to } 10 \text{ kHz}, \qquad \qquad C_{\text{ref}} = 5 \mu\text{F}$		86			"
Output regulation				-0.3		mV/V
Reference voltage, V <sub>ref</sub>				7.15		V
Standby current	V <sub>I</sub> = 30 V,	I <sub>O</sub> = 0		2.3		mA
Short-circuit output current	$R_{SC} = 10 \Omega$	V <sub>O</sub> = 0		65		mA
Output naine valte re	BW = 100 Hz to 10 kHz,	$C_{ref} = 0$		20		μV
Output noise voltage	BW = 100 Hz to 10 kHz,	$C_{ref} = 5 \mu F$		2.5		μν

NOTES: 2. For all values in this table, the device is connected as shown in Figure 1 with the divider resistance as seen by the error amplifier  $\leq$  10 k $\Omega$ . Unless otherwise specified, V<sub>I</sub> = V<sub>CC+</sub> = V<sub>C</sub> = 12 V, V<sub>CC-</sub> = 0, V<sub>O</sub> = 5 V, I<sub>O</sub> = 1 mA, R<sub>SC</sub> = 0, and C<sub>ref</sub> = 0.

3. Pulse-testing techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.



<sup>†</sup> Full range for  $\mu$ A723C is 0°C to 70°C and for  $\mu$ A723M is –55°C to 125°C.

NOTES: 2. For all values in this table, the device is connected as shown in Figure 1 with the divider resistance as seen by the error amplifier  $\leq$  10 k $\Omega$ . Unless otherwise specified,  $V_I = V_{CC+} = V_C = 12$  V,  $V_{CC-} = 0$ ,  $V_O = 5$  V,  $V_{CC-} = 0$ , and  $V_{CC-} = 0$ .

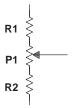
<sup>3.</sup> Pulse-testing techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.

Table 1. Resistor Values ( $k\Omega$ ) for Standard Output Voltages

OUTPUT VOLTAGE	APPLICABLE FIGURES	FIXED C	OUTPUT 5%	OUTPUT ADJUSTABLE ±10% (see NOTE 5)			
(V)	(see NOTE 4)	R1 (kΩ)	R2 (kΩ)	R1 (kΩ)	P1 (kΩ)	P2 (kΩ)	
3.0	1, 5, 6, 9, 11, 12 (4)	4.12	3.01	1.8	0.5	1.2	
3.6	1, 5, 6, 9, 11, 12 (4)	3.57	3.65	1.5	0.5	1.5	
5.0	1, 5, 6, 9, 11, 12 (4)	2.15	4.99	0.75	0.5	2.2	
6.0	1, 5, 6, 9, 11, 12 (4)	1.15	6.04	0.5	0.5	2.7	
9.0	2, 4, (5, 6, 9, 12)	1.87	7.15	0.75	1.0	2.7	
12	2, 4, (5, 6, 9, 12)	4.87	7.15	2.0	1.0	3.0	
15	2, 4, (5, 6, 9, 12)	7.87	7.15	3.3	1.0	3.0	
28	2, 4, (5, 6, 9, 12)	21.0	7.15	5.6	1.0	2.0	
45	7	3.57	48.7	2.2	10	39	
75	7	3.57	78.7	2.2	10	68	
100	7	3.57	105	2.2	10	91	
250	7	3.57	255	2.2	10	240	
-6 (see Note 6)	3, 10	3.57	2.43	1.2	0.5	0.75	
-9	3, 10	3.48	5.36	1.2	0.5	2.0	
-12	3, 10	3.57	8.45	1.2	0.5	3.3	
-15	3, 10	3.57	11.5	1.2	0.5	4.3	
-28	3, 10	3.57	24.3	1.2	0.5	10	
-45	8	3.57	41.2	2.2	10	33	
-100	8	3.57	95.3	2.2	10	91	
-250	8	3.57	249	2.2	10	240	

NOTES: 4. The R1/R2 divider may be across either V<sub>O</sub> or V<sub>(ref)</sub>. If the divider is across V<sub>(ref)</sub>, use the figure numbers without parentheses. If the divider is across V<sub>O</sub>, use the figure numbers in parentheses.

5. To make the voltage adjustable, the R1/R2 divider shown in the figures must be replaced by the divider shown below.



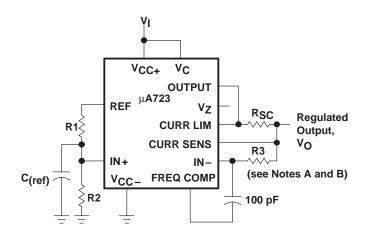
### **Adjustable Output Circuit**

6. For Figures 3, 8, and 10, the device requires a minimum of 9 V between  $V_{CC+}$  and  $V_{CC-}$  when  $V_{O}$  is equal to or more positive than -9 V.

**Table 2. Formulas for Intermediate Output Voltages** 

Outputs from 2 V to 7 V See Figures 1, 5, 6, 9, 11, 12 (4) and Note 4	Outputs from 4 V to 250 V See Figure 7 and Note 4	Current Limiting
$V_{O} = V_{(ref)} \times \frac{R2}{R1 + R2}$	$V_O = \frac{V(ref)}{2} \times \frac{R2-R1}{R1}$	$I_{\text{(limit)}} \approx \frac{0.65 \text{ V}}{R_{\text{SC}}}$
	R3 = R4	
Outputs from 7 V to 37 V See Figures 2, 4, (5, 6, 9, 11, 12) and Note 4	Outputs from -6 V to -250 V See Figures 3, 8, 10 and Notes 4 and 6	Foldback Current Limiting See Figure 6
$V_O = V_{(ref)} \times \frac{R1 + R2}{R2}$	$V_O = -\frac{V(ref)}{2} \times \frac{R1 + R2}{R1}$	$I_{\text{(knee)}} \approx \frac{V_{\text{O}}R3 + (R3 + R4) \ 0.65 \ V}{R_{\text{SC}}R4}$
	R3 = R4	$I_{OS} \approx \frac{0.65 \text{ V}}{R_{SC}} \times \frac{R3 + R4}{R4}$

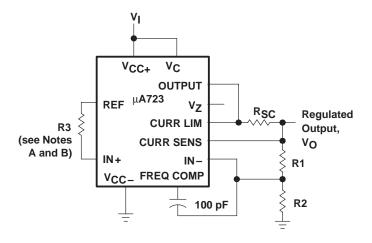
- NOTES: 4. The R1/R2 divider can be across either  $V_O$  or  $V_{(ref)}$ . If the divider is across  $V_{(ref)}$ , use figure numbers without parentheses. If the divider is across  $V_O$ , use the figure numbers in parentheses.
  - 6. For Figures 3, 8, and 10, the device requires a minimum of 9 V between V<sub>CC+</sub> and V<sub>CC-</sub> when V<sub>O</sub> is equal to or more positive than -9 V.



NOTES: A. R3 =  $\frac{R1 \times R2}{R1 + R2}$  for minimum  $\alpha_{VO}$ 

B. R3 may be eliminated for minimum component count. Use direct connection (i.e.,  $R_3 = 0$ ).

Figure 1. Basic Low-Voltage Regulator (V<sub>O</sub> = 2 V to 7 V)



NOTES: A. R3 =  $\frac{R1 \times R2}{R1 + R2}$  for minimum  $\alpha_{\mbox{VO}}$ 

B. R3 may be eliminated for minimum component count. Use direct connection (i.e.,  $R_3 = 0$ ).

Figure 2. Basic High-Voltage Regulator  $(V_O = 7 \text{ V to } 37 \text{ V})$ 

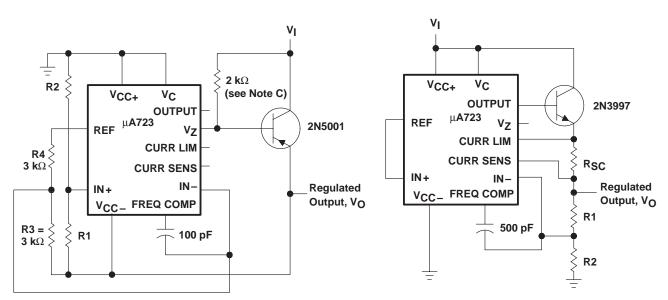


Figure 3. Negative-Voltage Regulator

Figure 4. Positive-Voltage Regulator (External N-P-N Pass Terminator)

NOTE A: When 10-lead μA723U devices are used in applications requiring V<sub>Z</sub>, an external 6.2-V regulator diode must be connected in series with OUTPUT.

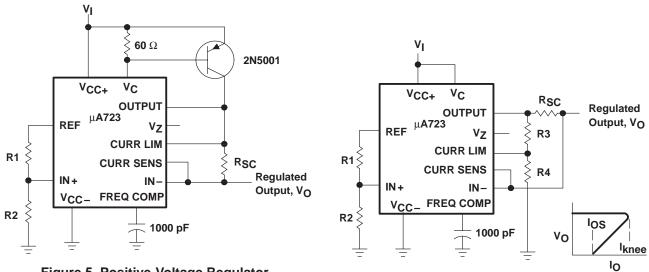
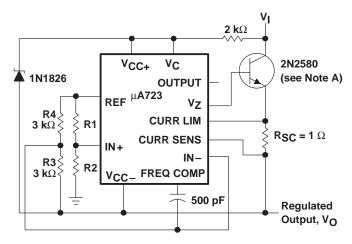


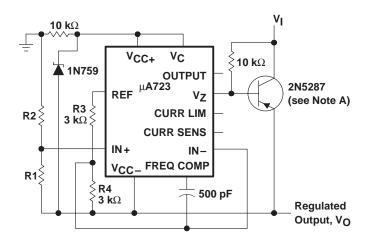
Figure 5. Positive-Voltage Regulator (External P-N-P Pass Transistor)

Figure 6. Foldback Current Limiting



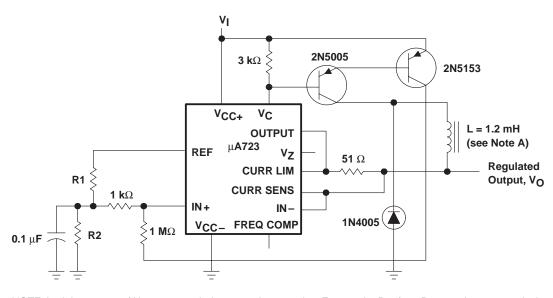
NOTE A: When 10-lead  $\mu$ A723U devices are used in applications requiring V<sub>Z</sub>, an external 6.2-V regulator diode must be connected in series with OUTPUT.

Figure 7. Positive Floating Regulator



NOTE A: When 10-lead  $\mu A723U$  devices are used in applications requiring V<sub>7</sub>, an external 6.2-V regulator diode must be connected in series with OUTPUT.

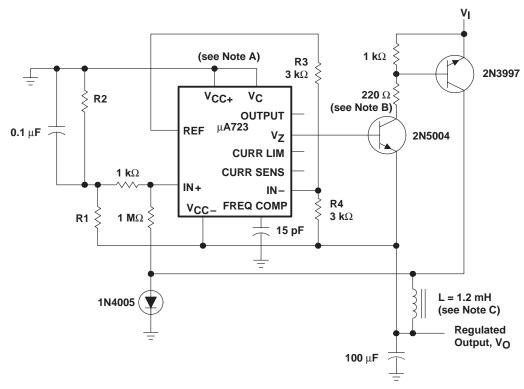
Figure 8. Negative Floating Regulator



NOTE A: L is 40 turns of No. 20 enameled copper wire wound on Ferroxcube P36/22-3B7 potted core or equivalent, with a 0.009-inch air gap.

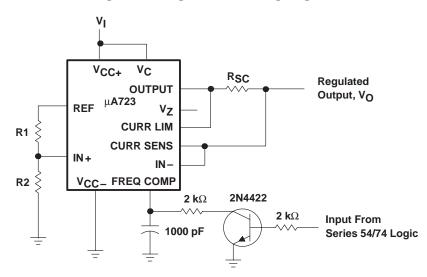
Figure 9. Positive Switching Regulator





- NOTES: A. The device requires a minimum of 9 V between  $V_{CC+}$  and  $V_{CC-}$  when  $V_O$  is equal to or more positive than -9 V.
  - B. When 10-lead µA723U devices are used in applications requiring V<sub>Z</sub>, an external 6.2-V regulator diode must be connected in series with OUTPUT.
  - C. L is 40 turns of No. 20 enameled copper wire wound on Ferroxcube P36/22-3B7 potted core or equivalent, with a 0.009-inch air gap.

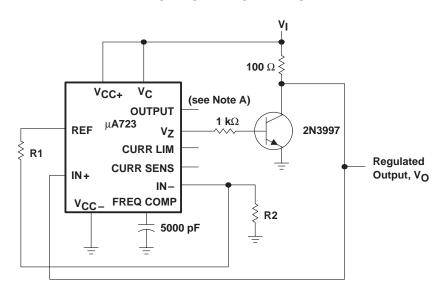
Figure 10. Negative Switching Regulator



NOTE A: A current-limiting transistor can be used for shutdown if current limiting is not required.

Figure 11. Remote Shutdown Regulator With Current Limiting





NOTE A: When 10-lead  $\mu$ A723U devices are used in applications requiring V<sub>Z</sub>, an external 6.2-V regulator diode must be connected in series with OUTPUT.

Figure 12. Shunt Regulator



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